

ANTREX Electronics

Electronic Components Sourcing Information

Product Reference Information

Part Number: 1N2256A
Manufacturer: Microchip Technology
Package: DO-203AA, DO-4, Stud
Availability: Please confirm with sales

Product Page:

<https://antrexco.com/product/details/microchip-technology/1n2256a.html>

Request a Quote:

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Quality & Trust

New & Original Components

Supplier verification and packaging condition review

CoC / RoHS / REACH documents available on request

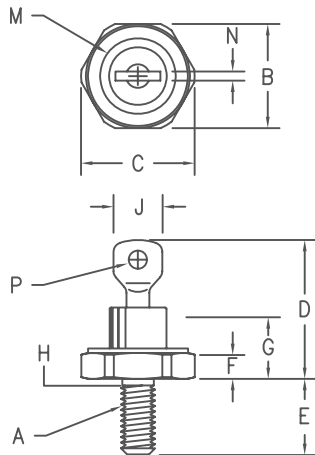
Secure sourcing support for OEM / EMS projects

Note:

This PDF includes an ANTREX product reference cover page.

The original manufacturer datasheet follows from the next page.

Silicon Power Rectifier S/R21 Series



Notes:

- 10-32 UNF3A
- Full threads within 2 1/2 threads
- Standard Polarity: Stud is Cathode
Reverse Polarity: Stud is Anode

Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	---	---	---	---	1
B	.424	.437	10.77	11.10	
C	---	.505	---	12.82	
D	.600	.800	15.24	20.32	
E	.422	.453	10.72	11.50	
F	.075	.175	1.91	4.44	
G	---	.405	---	10.29	
H	.163	.189	4.15	4.80	2
J	---	.310	---	7.87	
M	---	.350	---	8.89	Dia
N	.020	.065	.510	1.65	
P	.070	.100	1.78	2.54	Dia

D0203AA (D04)

Microsemi Catalog Number	JEDEC Numbers	Peak Reverse Voltage
1N2246,A	1N2598	50V
1N2248,A		100V
		150V
*S2120	1N2250,A	200V
	1N2252,A	300V
*S2140	1N2254,A	400V
	1N2256,A	500V
*S2160	1N2258,A	600V
		700V
*S2180	1N2260,A	800V
	1N3670,A	900V
	1N3671,A	1000V
*S21100	1N2262,A	1200V
*S21120	1N2264,A	1400V
*S21140		1600V
*S21160	1N5331	

*Change S to R in part number for Reverse Polarity
For 1N types, use an R suffix for Reverse Polarity

- Glass Passivated Die
- Low Forward Voltage
- 250A Surge Rating
- Glass to metal seal construction
- V_{RRM} to 1600V
- Low cost Non-RoHS package

Electrical Characteristics

Average forward current	IF(AV) 22 Amps	$T_C = 134^{\circ}\text{C}$, half sine wave, $R_{\theta JC} = 2.5^{\circ}\text{C/W}$
Maximum surge current	IFSM 250 Amps	8.3ms, half sine, $T_J = 200^{\circ}\text{C}$
Max I^2t for fusing	I^2t 260 A ² s	
Max peak forward voltage	V_{FM} 1.2 Volts	$I_{FM} = 30\text{A}; T_J = 25^{\circ}\text{C}$
Max peak reverse current	IRM 10 μA	$V_{RRM}, T_J = 25^{\circ}\text{C}$
Max peak reverse current	IRM 1.0 mA	$V_{RRM}, T_J = 150^{\circ}\text{C}$
Max Recommended Operating Frequency	10kHz	

*Pulse test: Pulse width 300 μsec . Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temperature range	T_{STG}	-65°C to 200°C
Operating junction temp range	T_J	-65°C to 200°C
Maximum thermal resistance	$R_{\theta JC}$	2.5°C/W Junction to Case
Mounting torque		25-30 inch pounds
Weight		.16 ounces (5.0 grams) typical

S/R21

Figure 1
Maximum Forward Characteristics

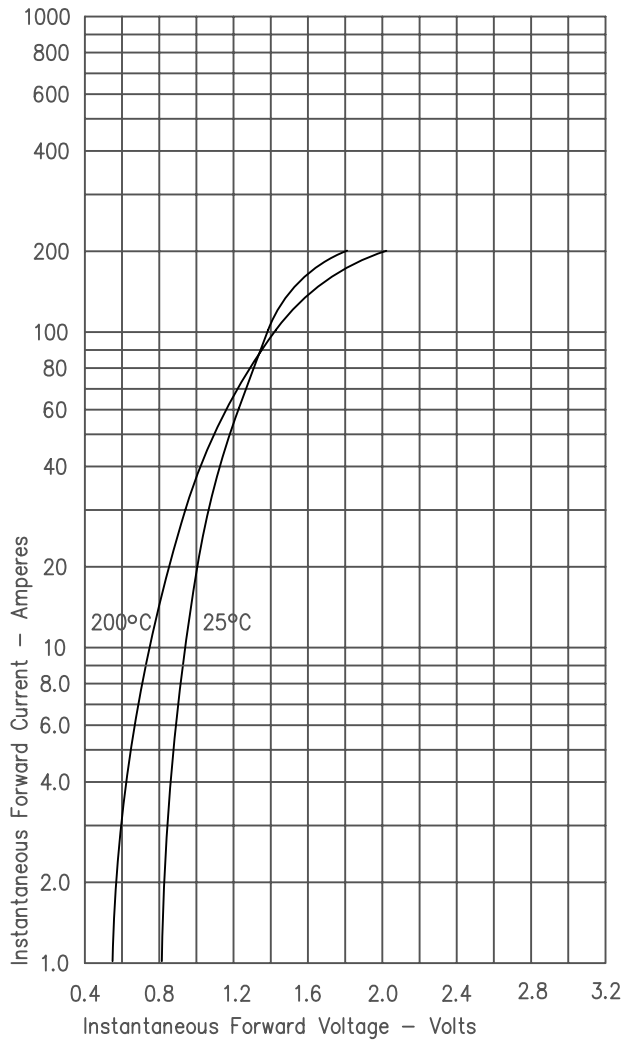


Figure 3
Forward Current Derating

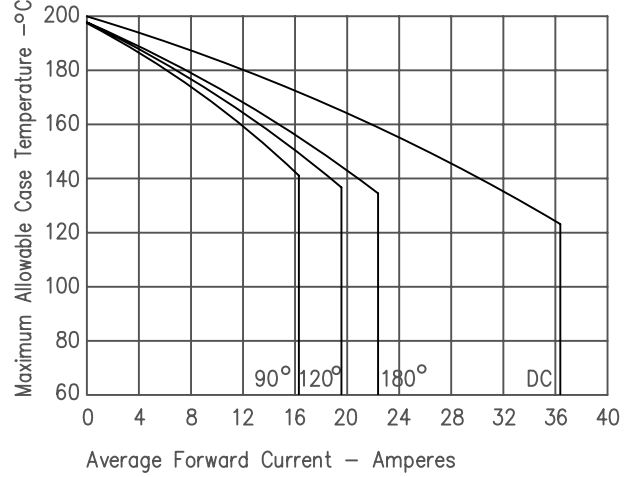


Figure 4
Maximum Forward Power Dissipation

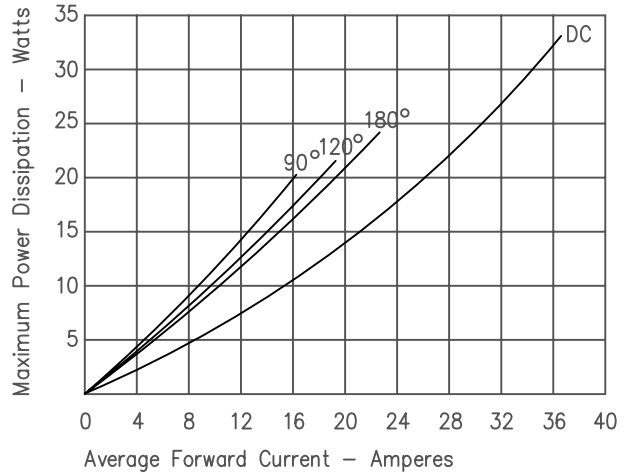


Figure 2
Typical Reverse Characteristics

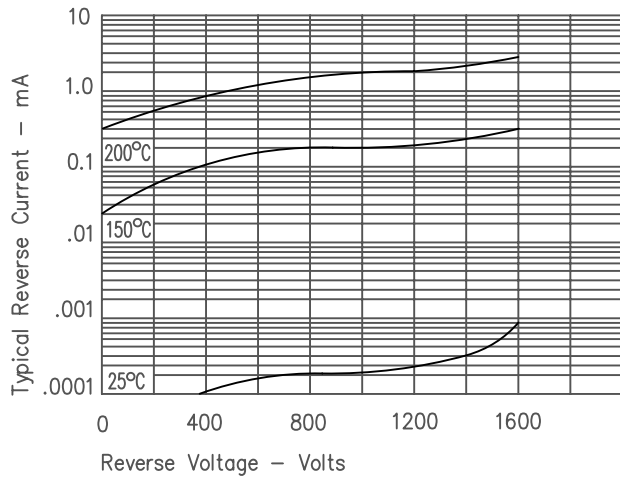


Figure 5
Transient Thermal Impedance

